## **CLAIM AMENDMENTS**

Please amend the claims as described below. In accordance with 37 CFR §1.121, a complete listing of all claims in the application is provided below. Notably, the status of each claim is indicated in the parenthetical expression adjacent to the corresponding claim number.

## Claims 1-35 (Canceled).

chamber.

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- 1 36. (Currently Amended) An electromechanical device comprising: 2 a substrate; a mechanical structure disposed over the substrate wherein a monolayer or self-3 assembled layer is disposed on at least a portion of the mechanical structure; 4 5 a film encapsulation structure, disposed over the mechanical structure, to define and seal a chamber: 6 7 an anti-stiction channel, etched into the film encapsulation structure, to provide access to at least a portion of the mechanical structure disposed in the chamber; and 8 an anti-stiction plug, disposed over or in the anti-stiction channel, to re-seal the 9
- 1 37. (**Previously Presented**) The device of claim 36 wherein the film encapsulation 2 structure includes first and second encapsulation layers.
- 38. (**Previously Presented**) The device of claim 37 wherein the first encapsulation layer includes polycrystalline silicon, porous polycrystalline silicon, amorphous silicon, silicon carbide, silicon nitride, silicon/germanium, germanium, or gallium arsenide.

- 1 (Previously Presented) The device of claim 37 wherein the second 39. 2 encapsulation layer includes polycrystalline silicon, porous polycrystalline silicon, 3 amorphous silicon, germanium, silicon/germanium, gallium arsenide, or silicon carbide. 1 40. (Previously Presented) The device of claim 36 wherein the anti-stiction plug 2 includes spin-on polymer, SOG or a metal material. 41. (Previously Presented) The device of claim 36 wherein the anti-stiction plug 1 2 includes spin-on polymer or SOG which is deposited using silk screening. 1 42. (Previously Presented) The device of claim 36 wherein the anti-stiction plug 2 includes spin-on polymer or SOG which is deposited using dispensed seal-glass, plastic 3 and/or epoxy. 1 43. (Previously Presented) The device of claim 36 wherein the anti-stiction plug is 2 deposited using a shadow mask technology. 1 44. (Previously Presented) The device of claim 36 further including a trap, 2 disposed between the anti-stiction channel and the mechanical structure.
- 1 45. (**Previously Presented**) The device of claim 44 wherein the trap is a 2 substantially vertical trap.

- 1 46. (**Previously Presented**) The device of claim 44 wherein the trap is a 2 substantially horizontal trap.
- 1 47. (**Previously Presented**) The device of claim 36 further including a diffusion 2 barrier disposed over the anti-stiction plug.
- 1 48. (**Previously Presented**) The device of claim 47 wherein the diffusion barrier includes a metal material.

Claims 49-62 (Canceled).

- 1 63. (Currently Amended) An electromechanical device comprising:
- 2 a substrate;
- a mechanical structure disposed over the substrate wherein an anti-stiction layer is
- 4 disposed on at least a portion of the mechanical structure;
- 5 a film encapsulation structure, disposed over the mechanical structure, to define, in
- 6 part, a chamber;
- 7 an anti-stiction channel, formed in the film encapsulation structure, to allow the anti-
- 8 stiction layer to be disposed on at least the portion of the mechanical structure disposed in
- 9 the chamber; and
- an anti-stiction plug, disposed over or in the anti-stiction channel, to re-seal the
- 11 chamber.

1	64. (Previously Presented) The device of claim 63 wherein the film encapsulation
2	structure includes first and second encapsulation layers.
1	65. (Previously Presented) The device of claim 64 wherein the first encapsulation
2	layer includes polycrystalline silicon, porous polycrystalline silicon, amorphous silicon,
3	silicon carbide, silicon nitride, silicon/germanium, germanium, or gallium arsenide.
1	66. (Previously Presented) The device of claim 64 wherein the second
2	encapsulation layer includes polycrystalline silicon, porous polycrystalline silicon,
3	amorphous silicon, germanium, silicon/germanium, gallium arsenide, or silicon carbide.
1	67. (Previously Presented) The device of claim 63 wherein the anti-stiction plug
2	includes spin-on polymer, SOG or a metal material.
1	68. (Previously Presented) The device of claim 63 wherein the anti-stiction plug
2	includes spin-on polymer or SOG which is deposited using silk screening.
1	69. (Previously Presented) The device of claim 63 wherein the anti-stiction plug
2	includes spin-on polymer or SOG which is deposited using dispensed seal-glass, plastic
3	and/or epoxy.
1	70. (Previously Presented) The device of claim 63 wherein the anti-stiction plug is
2	deposited using a shadow mask technology.

1 71. (Previously Presented) The device of claim 63 further including a trap, 2 disposed between the anti-stiction channel and the mechanical structure. 1 72. (Previously Presented) The device of claim 71 wherein the trap is a 2 substantially vertical trap. 73. (Previously Presented) The device of claim 71 wherein the trap is a 1 2 substantially horizontal trap. 74. (Previously Presented) The device of claim 71 wherein the trap includes a 1 2 substantially horizontal portion and a substantially vertical portion. 75. (Previously Presented) The device of claim 63 further including a diffusion 1 2 barrier disposed over the anti-stiction plug. 1 76. (Previously Presented) The device of claim 75 wherein the diffusion barrier is 2 a metal layer. 1 77. (Previously Presented) The device of claim 63 wherein the anti-stiction layer is a monolayer or self-assembled layer. 2